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PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of	Docket No: Q81061
Hideki HAYASHIDA, et al.	Allowed: September 23, 2005
Appln. No.: 10/821,944	Group Art Unit: 2818
Confirmation No.: 2372	Examiner: David NHU
Filed: April 12, 2004	
For: AMMONIA FOR USE IN MANUFACTURING OF GAN-TYPE COMPOUND SEMICONDUCTOR AND METHOD FOR MANUFACTURING GAN-TYPE COMPOUND SEMICONDUCTOR	

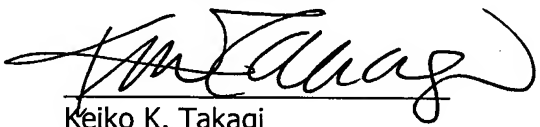
REQUEST FOR ACKNOWLEDGEMENT OF DRAWING

MAIL STOP ISSUE FEE
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Applicants respectfully request the Examiner to acknowledge the two (2) sheets of drawings submitted on April 12, 2004, and the Replacement sheet filed on September 9, 2005, copies of which are submitted herewith, at the Examiner's earliest convenience.

Respectfully submitted,


Keiko K. Takagi
Registration No. 47,121

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WASHINGTON OFFICE

23373
CUSTOMER NUMBER

Date: October 21, 2005



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REQUEST OF EARLY NOTIFICATION OF SERIAL NUMBER
Rule 53(b) Continuation of U.S. Application. No. 09/473,708 filed December 29, 1999

Inventor(s): Hideki HAYASHIDA, et al.

Title: AMMONIA FOR USE IN MANUFACTURE OF GAN-TYPE
COMPOUND SEMICONDUCTOR AND METHOD FOR
MANUFACTURING GAN-TYPE COMPOUND SEMICONDUCTOR

Atty Doc. #: Q81061 Client: SHOWA DENKO K.K.
Filing Date: April 12, 2004 # Pgs. Spec/Abst: 19/1 #Claims: 1

Dwg. Sheets: 2 (Figs. 1-4) Decl Copy (4 pages) Prelim Amdt No

IDS/Prior Art: Yes PTO/SB/08 A & B (modified)
Pr Doc: None Asgmt: In the Parent Fee: \$770.00
Copy of Verified English translation of U.S. 60/114,376

☒ Check Attached ☐ Charge to Deposit # 19-4880 Atty/Sec: BEK/lin

SERIAL NO.:

CONF NO.:





SUGHRUE MION, PLLC

Continuation Application of U.S. Application No. 09/473,708

Q81061

Base Fee

\$770.00

TOTAL FILING FEE

\$770.00

A check for the statutory fee of \$770.00 is attached. The USPTO is directed and authorized to charge all required fees, except for the Issue Fee and the Publication Fee, to Deposit Account No. 19-4880. Please also credit any overpayments to said Deposit Account. A duplicate copy of this transmittal letter is attached.

The application is timely filed.

Respectfully submitted,

SUGHRUE MION, PLLC
Attorneys for Applicant

By Bruce E. Kramer
Bruce E. Kramer
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Date: April 12, 2004

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FILING RECEIPT
PLEASE DATE STAMP AND RETURN TO US - BOX 235X

In re application of

HAYASHIDA, Hideki, et al.

Appln. No.: 10/821,944

Group Art Unit: 2818

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PAPERS FILED ENTITLED:

- 1. Amendment Under 37 C.F.R. §1.111 (15 pages) along with 1 marked-up sheet and 1 replacement sheet of drawings**
- 2. Terminal Disclaimer**
- 3. Submission of Terminal Disclaimer (in duplicate with Check No. 280672 in the amount of \$130.00).**

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DOCKET NO.: Q81061

ATTORNEY/SEC: BEK/KKT

Date Filed: September 9, 2005

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CUSTOMER NUMBER

